

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
60V	2Ω @ V <sub>GS</sub> = 10V	320mA
607	3Ω @ V <sub>GS</sub> = 5V	260mA

#### Description

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- Motor Control
- **Power Management Functions**

#### **Features**

- Low On-Resistance: RDS(ON)
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

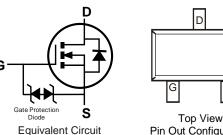
- Case: SOT-523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)





SOT-523

Top View



Pin Out Configuration

### Ordering Information (Note 4)

Dort Number	Cana	Deckering
Part Number	Case	Packaging
DMN63D1LT-7	SOT-523	3000/Tape & Reel
DMN63D1LT-13	SOT-523	10000/Tape & Reel

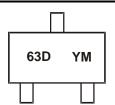
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### Marking Information



#### Date Code Kev

Balo Codo Hoy												
Year	2014	:	2015	2016		2017	2018		2019	2020		2021
Code	В		С	D		E	F		G	Н		I
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

1 of 6 www.diodes.com

<sup>63</sup>D = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015)M = Month (ex: 9 = September)



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	60	V		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V		
		$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	320 260	mA
Maximum Continuous Body Diode Forward Curren	t (Note 6)	Is	0.5	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 10	%)	I <sub>DM</sub>	1.2	А	

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	260	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>0JA</sub>	497	°C/W
Total Power Dissipation (Note 6)		PD	330	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	389	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

		0			0	·
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60		—	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1.0	μΑ	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>			±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0	1.6	2.5	V	$V_{DS} = 10V, I_D = 1mA$
Static Drain-Source On-Resistance				2.0	Ω	$V_{GS} = 10V, I_D = 0.5A$
	R <sub>DS(ON)</sub>		_	3.0	12	$V_{GS} = 5V, I_D = 0.05A$
Forward Transfer Admittance	Y <sub>fs</sub>	80		_	mS	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage	V <sub>SD</sub>		0.75	1.2	V	$V_{GS} = 0V, I_S = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		30	_	pF	
Output Capacitance	Coss		4.2	—	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss		2.9	_	pF	1 = 1:00012
Gate Resistance	Rg		133	_	Ω	$f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$
Total Gate Charge	Qg		392	_	рС	
Gate-Source Charge	Qgs		157	—	рС	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 250mA
Gate-Drain Charge	Q <sub>gd</sub>		92	—	рС	$D = 230 \Pi A$
Turn-On Delay Time	t <sub>D(ON)</sub>		3.9	_	ns	
Turn-On Rise Time	t <sub>R</sub>		3.4	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>		15.7	_	ns	$R_{G} = 25\Omega, I_{D} = 200 \text{mA}$
Turn-Off Fall Time	t <sub>F</sub>		9.9	_	ns	

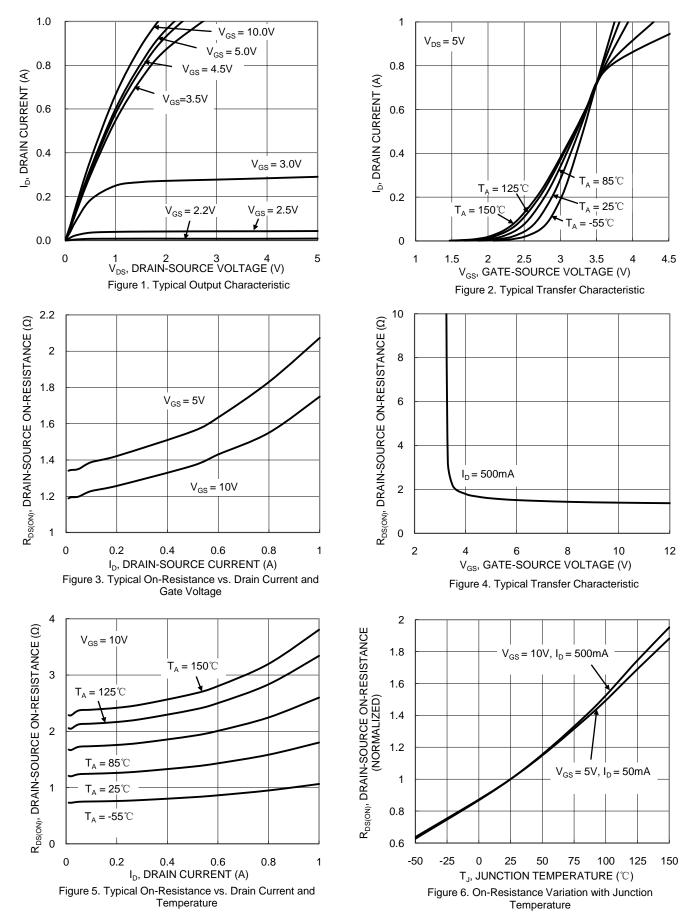
Notes:

5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

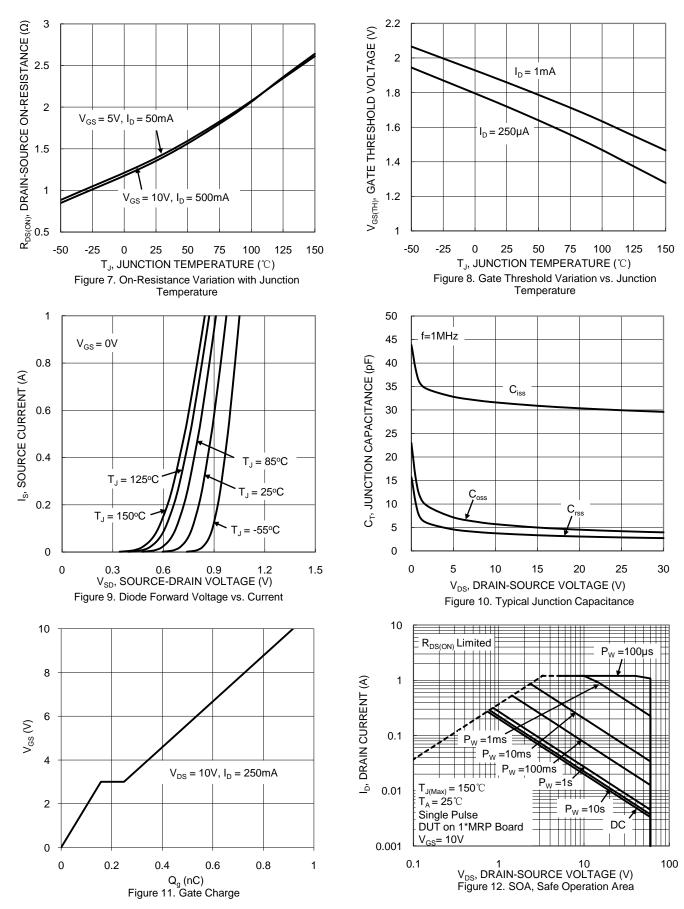




DMN63D1LT Document number: DS37551 Rev. 2 - 2

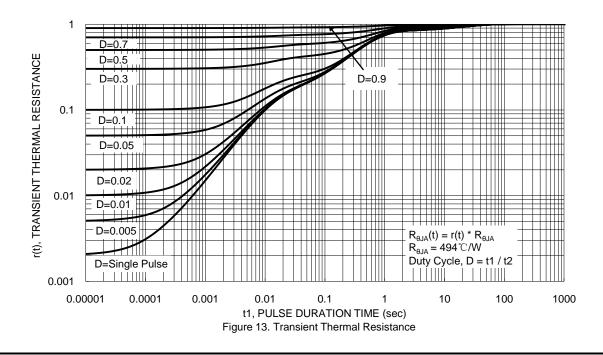


# DMN63D1LT



DMN63D1LT Document number: DS37551 Rev. 2 - 2 4 of 6 www.diodes.com November 2015 © Diodes Incorporated

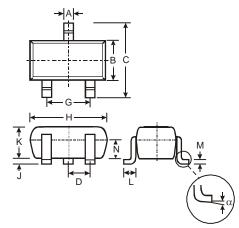




# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

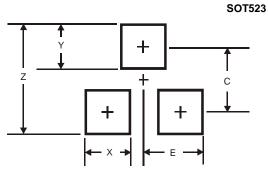
SOT523



SOT523							
Dim	Min	Max	Тур				
Α	0.15	0.30	0.22				
В	0.75	0.85	0.80				
С	1.45	1.75	1.60				
D	_	_	0.50				
G	0.90	1.10	1.00				
Н	1.50	1.70	1.60				
J	0.00	0.10	0.05				
Κ	0.60	0.80	0.75				
L	0.10	0.30	0.22				
М	0.10	0.20	0.12				
Ν	0.45	0.65	0.50				
α	α 0° 8° —						
All Dimensions in mm							

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Y	0.51
С	1.3
E	0.7



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